

Midterm #2 Solutions – EECS 145L Fall 2003

1a	Properties that differ	Pt resistance thermometer	Thermocouple
	material	metal	semiconductor
	R with increasing T	linear increase	exponential decrease
	maximum temperature	high (800 °C)	low (100 °C)

[full credit for 2 correct different properties; 2 points off for each missing entry]

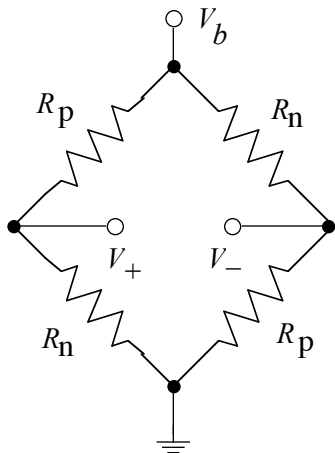
1b	Properties that differ	Incandescent lamp	Fluorescent lamp
	temperature	hot (3000K filament)	cool
	mechanism	black body radiation	discrete energy change of electrons
	wavelength spectrum	broad	discrete lines
	energy efficiency	low	high

[full credit for 2 correct different properties; 2 points off for each missing entry]

1c	Properties that differ	PIN photodiode	Light Emitting Diode (LED)
	input	photons	current
	output	current	photons
	electronic transducer type	sensor	actuator

[full credit for 2 correct different properties; 2 points off for each missing entry]

2a



The proper bridge circuit has the p-type gauges in opposing positions and the n-type gauges in opposing positions. Note that compression makes $\Delta R/R < 0$ for the p-type gauges and $\Delta R/R > 0$ for the n-type gauges.

2b

$$V_0 = \frac{R_n}{R_p + R_n} - \frac{R_p}{R_p + R_n} = \frac{(R + \Delta R_n) - (R + \Delta R_p)}{2R + \Delta R_p + \Delta R_n}$$

$$V_0 = \frac{\Delta R_n / R - \Delta R_p / R}{2 + \Delta R_p / R + \Delta R_n / R} = \frac{200\Delta L / L}{2 + 20,000(\Delta L / L)^2} = \frac{100\Delta L / L}{1 + 10,000(\Delta L / L)^2}$$

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[6 points off for not writing down the bridge equation]

[4 points off for writing down the bridge equation but not correctly deriving $V_0(\Delta L/L)$]

[3 points off for $V_0 = 100 \Delta L/L$]

2 c For $V_b = 1$ volt, bridge sensitivity is 0.1 mV per μstrain

2 d For $L/L = 10^{-3}$, $V_0 = 99$ mV, which is 1 mV (1% or 10 μstrain) lower than the straight line extrapolation.

[A correct answer would have to be consistent with the answer to 2b]

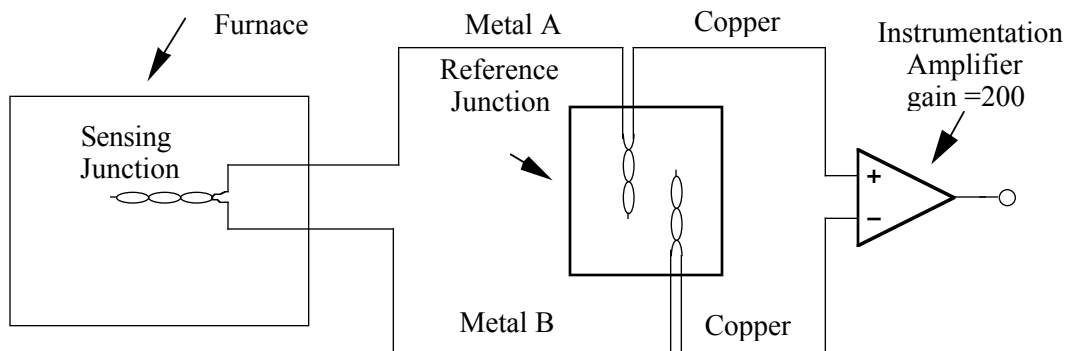
2 e 100 metric tons = 10^8 g, which exerts a force of 10^{11} dynes over 10^4 cm²

$$F/A = 10^7 \text{ dynes/cm}^2$$

$$\Delta L/L = (F/A)/E = 10^7 \text{ dynes/cm}^2 / 10^{11} \text{ dynes/cm}^2 = 10^{-4} = 100 \mu\text{strain}$$

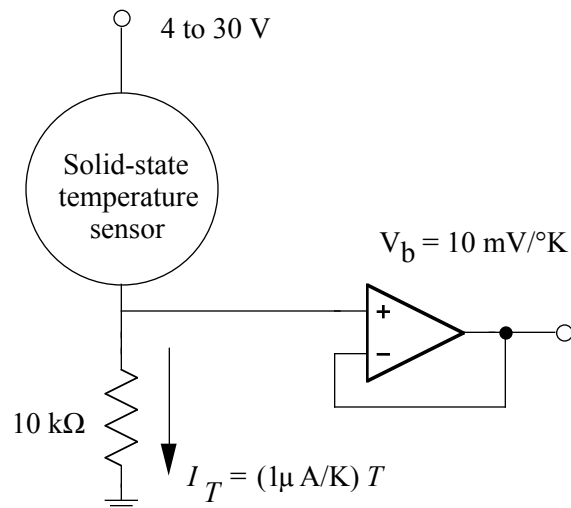
With a sensitivity of 0.1 mV/ μstrain , $V_0 = 10$ mV

3a



Since the thermocouple has a sensitivity of 50 $\mu\text{V}/^\circ\text{C}$, we need a differential gain of 200 to get the required 10 mV/ $^\circ\text{C}$

3b



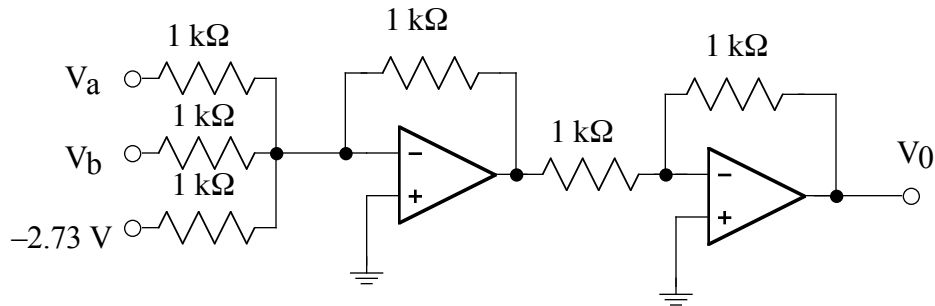
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With a sensitivity of $1 \mu\text{A/K}$, a series resistor of $10 \text{ k}\Omega$ will give us the required 10 mV/K . A buffer amplifier prevents loading of the summing amplifier, but was not required for full credit.

[2 points off for using a $1 \text{ k}\Omega$ resistor]

[4 points off for a design that does not specify the sensitivity]

3c



The output $V_0 = V_a + V_b - 2.73 \text{ V}$.

As a check, consider the following situation: The sensing and the reference junction are both at 0°C , so $V_a = 0.0 \text{ V}$. The solid state temperature sensor is at 273K and $V_b = 2.73\text{V}$. The above circuit produces $V_0 = 0.0 \text{ V}$, as desired.

[2 points off for omitting the 2.73 volt bias]

145L midterm #2 grade distribution:

				maximum score = 100
				average score = 89.3 (8.8 rms)
Problem				30-39 0 F
1	25.3(3.0 rms) (30 max)			40-49 0 D
2	35.8 (6.0 rms) (40 max)			50-59 0 C-
3	28.2 (3.1 rms) (30 max)			60-69 1 C
				70-79 2 B-
				80-89 6 B
				90-99 14 A
				100 1 A+